Seat No.:		Enrolment No			
		GUJARAT TECHNOLOGICAL UNIVERSITY BE - SEMESTER-III(New) • EXAMINATION – WINTER 2016			
Subject Code:2131006 Date:04/01/2 Subject Name:Electronic Devices and Circuits					
Tim	•	:30 AM to 01:00 PM Total Marks:	70		
	1. 2.	Attempt all questions. Make suitable assumptions wherever necessary. Figures to the right indicate full marks.			
Q.1		Short Questions	14		
	1	Knee voltage of germanium diode is then silicon diode.	14		
	2	In reverse bias current through diode is very			
	3 4	Frequency of full wave rectified voltage is If filter capacitance increased, diode forward bias period			
	5	Varactor diode is used in bias.			
	6	Size of collector is compare to emitter.			
	7	Transistor is on when it is operating in region.			
	8	Transistor collector current is when it is operating in cut off region.			
	9	For emitter bias, voltage at emitter is 0.7 less then voltage.			
	10	Current in a coupling capacitor circuit for high frequencies is			
	11 12	Input impedance of the base of an emitter follower is Audio amplifier operates in frequency range of			
	13	A JFET is controlled device.			
	14	Full form of CMOS is			
Q.2	(a)	Draw and explain full wave bridge rectifier.	04		
	(b)	Due to any cause R becomes 0 in fig. 1. What will be effect on diode and what will be diode voltage?	03		
	(c)	In fig. 2 what is maximum positive and negative output voltage? Sketch the output waveforms.	07		
	(-)	OR	07		
	(c)	Draw half wave rectifier circuit. Draw waveform for voltage across diode, diode current with R and RC load.	07		
Q.3	(a)	Explain transistor construction with size and doping level of each region.	03		
Q.D	(b)	What is voltage divider bias? What is its disadvantage? How it is removed with emitter bias?	07		
	(c)	What is base, collector and emitter voltage in fig.3. OR	04		
Q.3	(a)	How transistor act as a switch? What are limitations?	03		
	(b)	What is I_{CQ} , V_{CEQ} and r_c in fig. 4.	04		
	(c)	Explain transistor characteristics with clearly indicating saturation, active and cut off region. How load line is drawn in characteristics.	07		
Q.4	(a)	Explain Class AB operation of power amplifier.	03		
	(b)	Explain small signal common emitter amplifier. Transister in fig 5 has our action of 150 and gener voltage 7.5 What is	04		
	(c)	Transistor in fig.5 has current gain of 150 and zener voltage 7.5. What is output voltage, zener current and transistor power dissipation.	07		

Explain Class A operation of power amplifier.

Draw ac equivalent circuit of fig. 6.

Q.5 (a) Explain thermal runaway with respect to MOSFET.

Explain small signal common collector amplifier.

Q.4 (a)

(b)

(c)

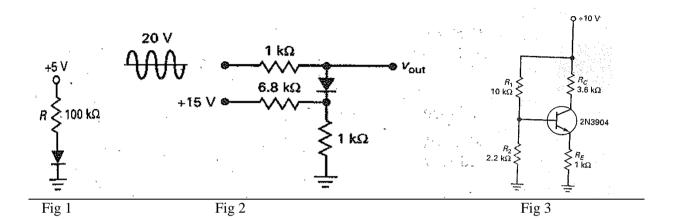
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04

07

03

	(b)	What is negative and positive feedback?	04
	(c)	Explain construction, operation and characteristics of JFET.	07
Q.5		OR	
	(a)	What are advantages of JFET over Bipolar Junction Transistor?	03
	(b)	How JFET are biased?	04
	(c)	What are different four types of feedback?	07



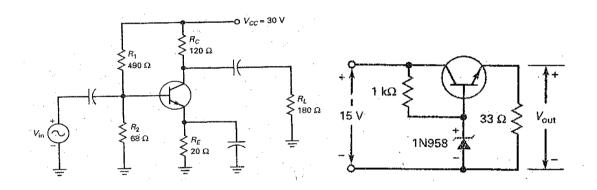


Fig 4 Fig 5

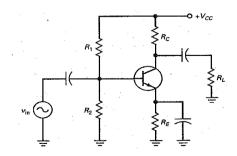


Fig.6